

Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)



Complete if Known	
Application Number	10/789,042
Filing Date	February 27, 2004
First Named Inventor	Ahn, Kie
Group Art Unit	2815
Examiner Name	Richards, N.

Sheet 1 of 2

Attorney Docket No: 1303.050US2

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EXAMINER *[Signature]*

DATE CONSIDERED

3/30/07

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>		Complete If Known	
		Application Number	10/789,042
		Filing Date	February 27, 2004
		First Named Inventor	Ahn, Kie
		Group Art Unit	2815
		Examiner Name	Richards, N.
Sheet 2 of 2		Attorney Docket No: 1303.050US2	

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NR		AWN, "ATOMIC LAYER DEPOSITED DIELECTRIC LAYERS", US Patent Application Serial No. 10/379,470, filed March 4, 2003	
NR		AWN, KIE Y., et al., "LANTHANIDE YTTRIUM ALUMINUM OXIDE DIELECTRIC FILMS", U.S. Application Serial No. 11/297,567, filed December 8, 2005	
NR		AWN, KIE Y., et al., "LANTHANUM ALUMINUM OXYNITRIDE DIELECTRIC FILMS", US Application Serial No 11/216474, filed August 31, 2005	
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EXAMINER

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S/N 10/789,042

PATENTIN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Kie Y. Ahn et al.

Examiner: N. D. Richards

Serial No.: 10/789,042

Group Art Unit: 2815

Filed: February 27, 2004

Docket: 1303.050US2

Title: LAALO₃ FILMS (AS AMENDED)COMMUNICATION CONCERNING RELATED APPLICATIONS

MS RCE

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related applications in the above-identified patent application:

Serial/Patent No.	Filing Date/Issue Date	Attorney Docket	Title
11496196	July 31, 2006	1303.068US4	MEMORY UTILIZING OXIDE-CONDUCTOR NANOLAMINATES
10443021 6970053	May 22, 2003	1303.137US1	ATOMIC LAYER DEPOSITION (ALD) HIGH PERMEABILITY LAYERED MAGNETIC FILMS TO REDUCE NOISE IN HIGH SPEED INTERCONNECTION
11063132 7154354	February 22, 2005	1303.137US2	HIGH PERMEABILITY LAYERED MAGNETIC FILMS TO REDUCE NOISE IN HIGH SPEED INTERCONNECTION
11197184	August 4, 2005	303.904US1	CONDUCTIVE NANOPARTICLES
11140643	May 27, 2005	1303.141US1	HAFNIUM TITANIUM OXIDE FILMS
11152759	June 14, 2005	1303.144US1	IRIDIUM / ZIRCONIUM OXIDE STRUCTURE
11459792	July 25, 2006	1303.092US2	ZrAl _x O _y DIELECTRIC LAYERS
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~~Continuations and divisionals may be later filed on the cases listed above, or cited to the Examiner in any previous Communication Concerning Related Applications. Applicants request that the Examiner review all continuations and divisionals of the above-listed or previously-cited patent applications before allowing the claims of the present patent application.~~

Respectfully submitted,
KIE Y. AHN ET AL.

By Applicants' Representatives,
SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.
P.O. Box 2938
Minneapolis, MN 55402
(612) 371-2157

Date 5 January 2007 By _____

David R. Cochran
Reg. No. 46,632

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: MS RCE, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 5 day of January, 2007.

LISA ROSENBERG
Name

Susan Rosenberg
Signature

considered by Examiner:

W. Schirmer 3/30/07